

HMC752LC4

Data Sheet

GaAs HEMT MMIC LOW NOISE AMPLIFIER, 24

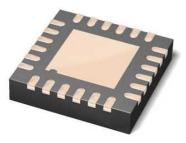
Manufacturers Analog Devices, Inc

Package/Case QFN24

Product Type RF Amplifiers

RoHS Pb-free Halide free

Please submit RFQ for HMC752LC4 or Email to us: sales@ovaga.com We will contact you in 12 hours.



Images are for reference only

RFO

General Description

Lifecycle

The HMC752LC4 is a GaAs MMIC Low Noise WidebandAmplifier housed in a leadless 4x4 mm ceramicsurface mount package. The amplifier operates between24 and 28 GHz, providing up to 25 dB of smallsignal gain, 2.5 dB noise figure, and output IP3 of+26 dBm, while requiring only 70 mA from a +3V supply. The P1dB output power of up to +13 dBm enablesthe LNA to function as a LO driver for balanced, I/Qor image reject mixers. The HMC752LC4 also featuresI/Os that are DC blocked and internally matched to 50 Ohms, making it ideal for high capacity microwaveradios or VSAT applications.

Features	Application

Noise Figure: 2.5 dB Point-to-Point Radios

Gain: 25 dB Point-to-Multi-Point Radios

P1dB Output Power: +13 dBm Military & Space

Supply Voltage: +3V @ 70 mA Test Instrumentation

Output IP3: +26 dBm

50 Ohm Matched Input/Output

24 Lead 4×4mm SMT Package: 16mm2

Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



Analog Devices, Inc QFN-16

HMC441LP3E



HMC253AQS24

Analog Devices, Inc

24-SSOP (0.154, 3.90mm Width)



HMC358MS8GE Analog Devices, Inc MSOP-8



HMC453ST89E
Analog Devices, Inc
ST89E



Analog Devices, Inc LP3

HMC948LP3E



HMC490
Analog Devices, Inc
SMD



Analog Devices, Inc QFN-16

HMC618ALP3E